

Abstract Submitted  
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**Band gap estimation in bilayer graphene through quantum capacitance measurement** KOSUKE NAGASHIO, TOMONORI NISHIMURA, AKIRA TORIUMI, University of Tokyo — The estimation of the quantum capacitance ( $C_Q$ ) through the capacitance measurement provides the direct information on Density of states ( $DOS$ ) in graphene since the energy cost to induce carriers is introduced as  $C_Q = e^2 DOS$  in series with the geometrical capacitance ( $C_{ox}$ ) in the equivalent circuit ( $1/C = 1/C_{ox} + 1/C_Q$ ). For bilayer graphene with  $Y_2O_3$  topgate structure, the band gap opening was qualitatively observed in DOS - energy relation estimated from  $C_Q$  under the large displacement. The band gap determined by  $C_Q$  was larger than the transport gap determined by variable-range hopping in gap states on IV measurement since carriers which respond to the alternating voltage are not required to transport throughout the device.

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